June 13th, 2023

δ-layer tunnel junctions in semiconductors for charge sensing

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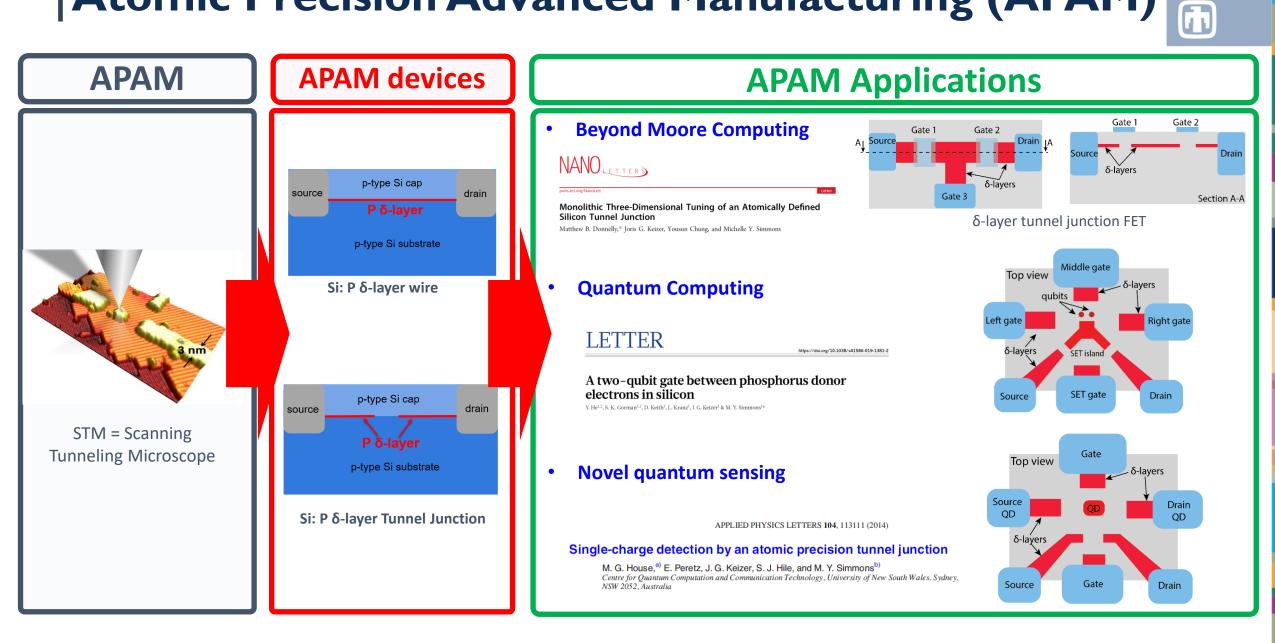


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Atomic Precision Advanced Manufacturing (APAM)



*Our computational approach for free electrons:

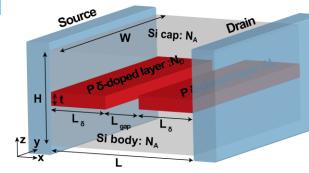
• Charge self-consistent NEGF implemented via Contact Block Reduction method scales linearly with the simulation volume O(V)

- Electron-electron interaction via DFT-LDA exchange-correlation
- Real-space scattering on discrete impurities
- Inelastic scattering via Matthiessen's rule and mobility models
- Kinetic energy term: the effective mass tensor

This approach allows to accurately represent all *open-system electron properties*: the current, current spectrum, transmission, LDOS.

*D. Mamaluy, J.P. Mendez *et al. Commun Phys* 4, 205 (2021) J.P. Mendez, D. Mamaluy, *Sci Rep* 12, 16397 (2022)

Prior simulations and confirmations





communications

physics

ARTICLE

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Check for updates

https://doi.org/10.1038/s42005-021-00705-1 OPEN

Revealing quantum effects in highly conductive $\delta\text{-layer systems}$

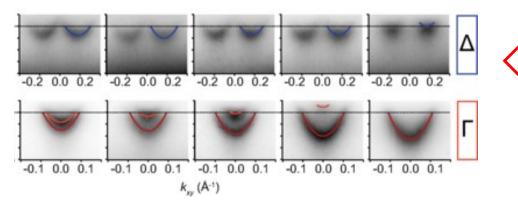
Denis Mamaluy₀ ^{1⊠}, Juan P. Mendez₀ ^{1⊠}, Xujiao Gao¹ & Shashank Misra¹

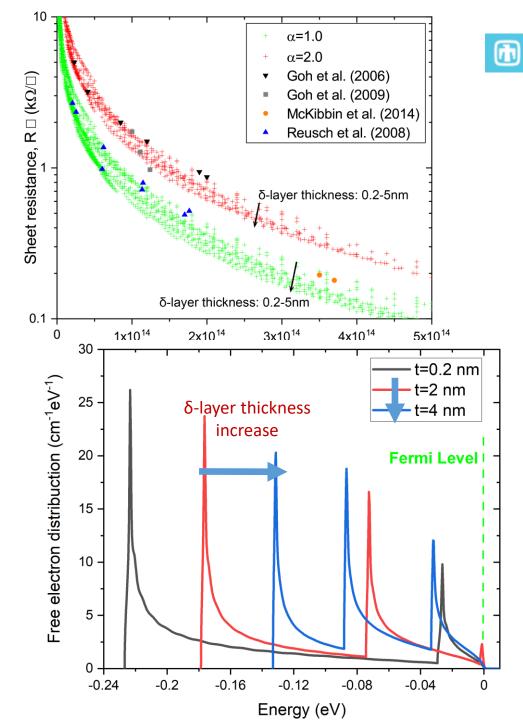
PHYSICAL REVIEW B 101, 121402(R) (2020)

Rapid Communications

Observation and origin of the Δ manifold in Si:P δ layers

Ann Julie Holt,¹ Sanjoy K. Mahatha⁰,¹ Raluca-Maria Stan,¹ Frode S. Strand,² Thomas Nyborg⁰,² Davide Curcio,¹ Alex K. Schenk,² Simon P. Cooil⁰,^{2,3} Marco Bianchi,¹ Justin W. Wells,² Philip Hofmann,¹ and Jill A. Miwa^{1,*}





Predictive quantum transport simulations



mod relaxation effects in the contacts [6].

Effective mass approaches are not predictive. $1 m_{e}^{[54,55]}$ NEG and At the 5nm scale a heterostructure does not only estimates the experimental tunneling resistances. Most effective mass models are limited in terms of capturing all the band minima at different k-points. We show in Figure 2a that there are several Γ and Δ band minima at different *k*-points, with a notable non-parabolicity of the bands at higher *k*. As a result, effective mass models will tend to underestimate the density of states in the leads, leading to an overestimation of the tunneling masses that cannot be predicted by bulk effective modeling resis R_T is .nge line) mass approaches. Atomistic basis sets are critically usinĮ The overneeded, even though transport might just happen in portance estin the conduction band. Effective mass models can be electronic of us tuned to specific atomistic representations but dispersion and 3D potential profile in which excellent agreement is achieved. Our results highlight the limitations of using single-band theories such as WKB and effective mass theory to model electron tunneling transport in highly doned

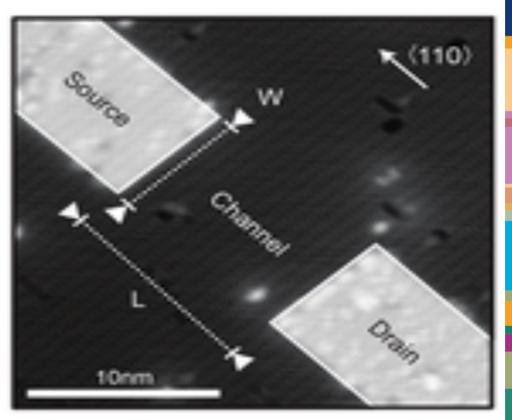
ADVANCED FUNCTIONAL **MATERIALS**

Research Article 🛛 🔂 Open Access 🛛 😨 🚯

Multi-Scale Modeling of Tunneling in Nanoscale Atomically Precise Si:P Tunnel Junctions

Matthew B. Donnelly 🔀, Mushita M. Munia, Joris G. Keizer, Yousun Chung, A. M. Saffat-Ee Huq, Edyta N. Osika, Yu-Ling Hsueh, Rajib Rahman, Michelle Y. Simmons 🔀

First published: 08 March 2023 | https://doi.org/10.1002/adfm.202214011



Simulations of modern GAA NSFETs with tight-binding codes are still too expensive SILVACO/NEMO5 scaling

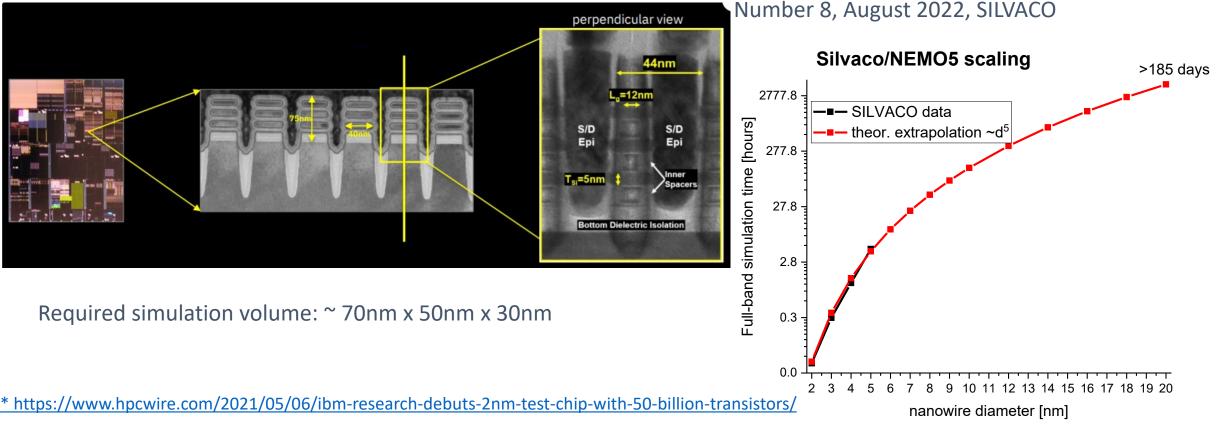
IBM, Intel and Samsung

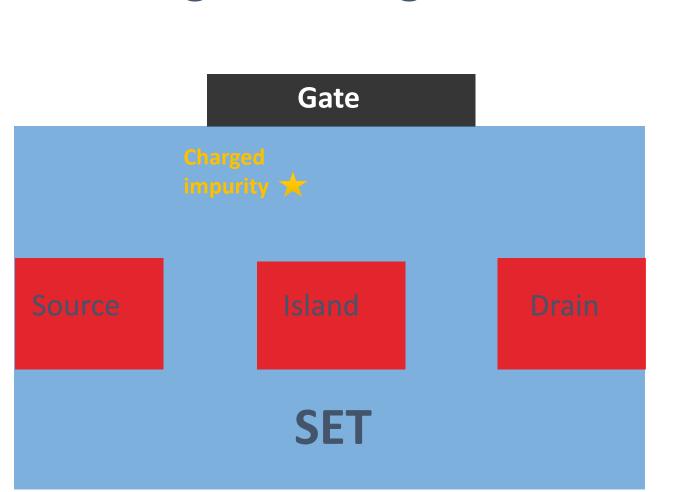
partnership*

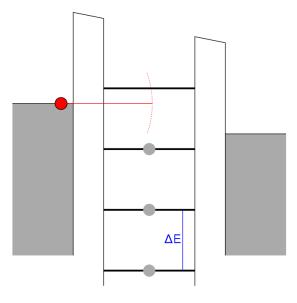


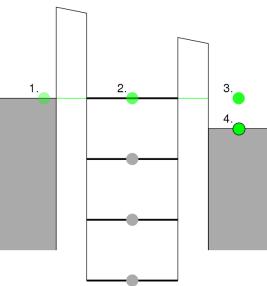
Source: "Quantum Transport Simulation at Atomistic Accuracy of a Nanowire FET",

Journal for Process and Device Engineers, Volume 32,





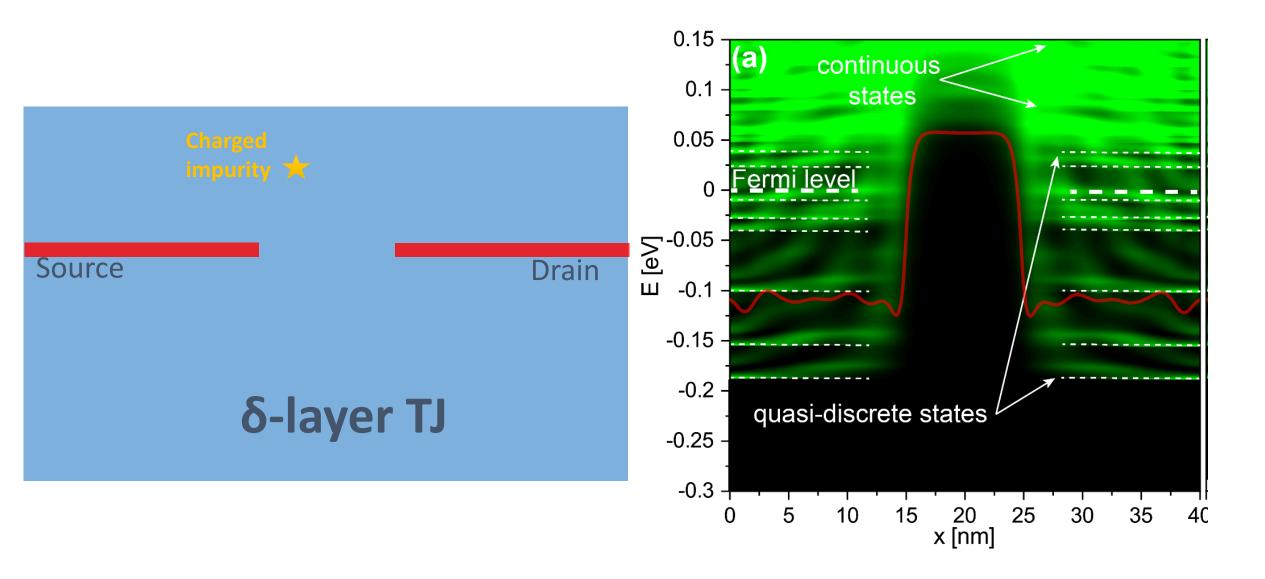






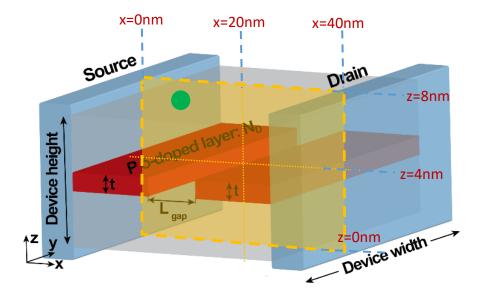


^ICharge sensing with δ -layer tunnel junction



δ -layer TJs are ultrasensitive to charges!





Applied voltage: 100mV HPC Cluster: SOLO ~ 700 simulations

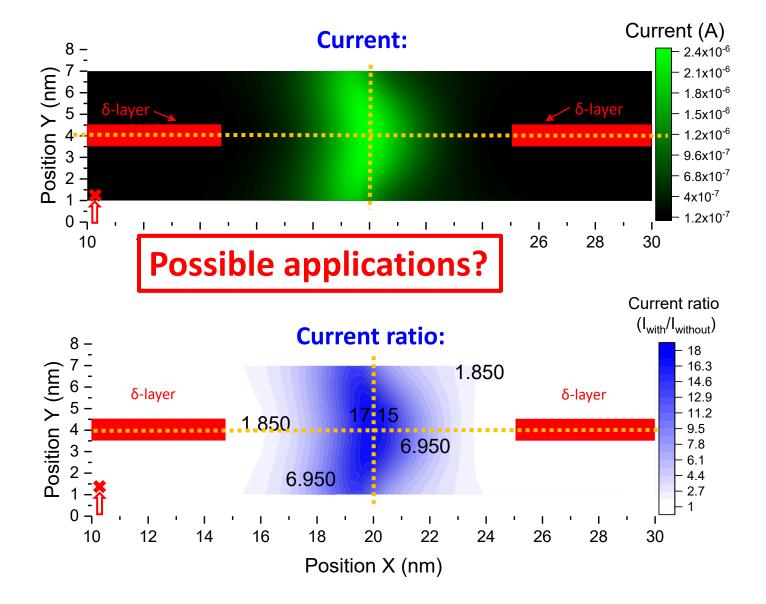
arXiv > cond-mat > arXiv:2209.11343

Condensed Matter > Mesoscale and Nanoscale Physics

[Submitted on 22 Sep 2022

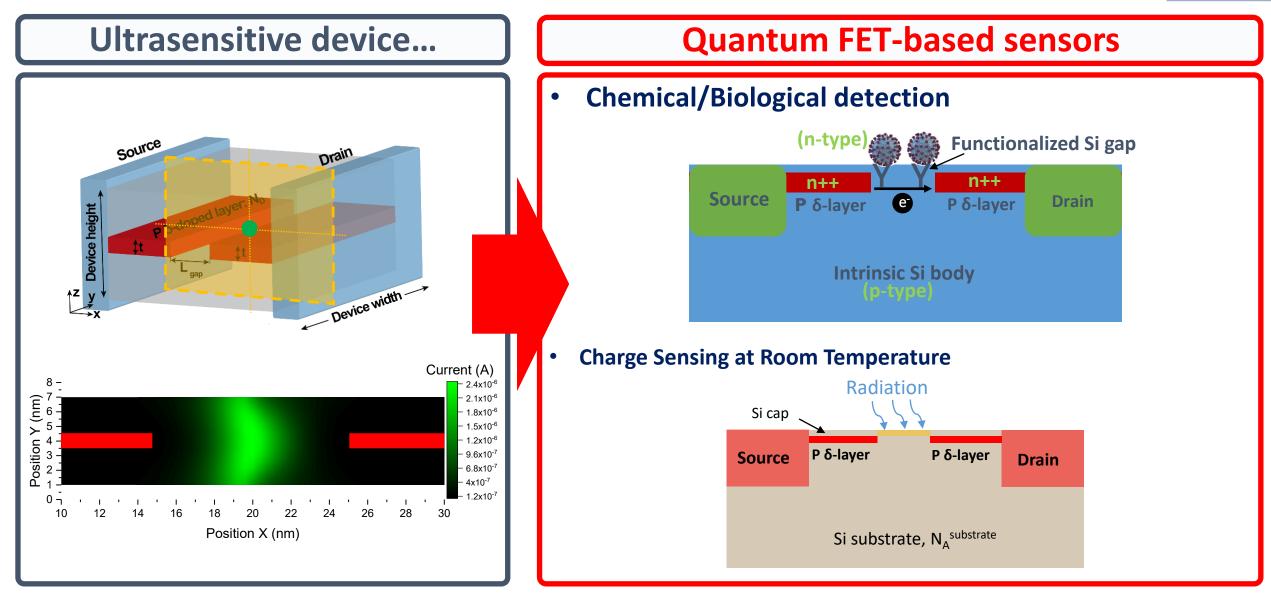
Influence of imperfections on tunneling rate in $\delta\text{-layer}$ junctions

Juan P. Mendez, Shashank Misra, Denis Mamaluy



δ -layer TJs are ultrasensitive to charges!







Conclusions

- 1) Highly-conducting highly-confined systems **require** an open-system treatment (e.g. NEGF) to correctly represent the number of occupied states, LDOS and current.
- 2) Kinetic energy operator with the effective mass tensor enables truly predictive *transport* simulations in silicon.
- 3) Quantum charge sensing is possible with extremely simple ("inverse-SET") structures, that are just δ -layer Tunnel Junctions. The effect is due to the conduction band quantization

